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APPLICATION NO.		FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/078,473		02/21/2002	Hoki Kwon	15436.438.1	4854
22913	7590	12/08/2005	EXAMINER		
WORKMA			NGUYEN,	NGUYEN, DUNG T	
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1000 EAGL			2828	-	
SALT LAK	E CITY,	UT 84111		DATE MAILED: 12/08/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	<u> </u>	Application No.	Applicant(s)					
		10/078,473	KWON, HOKI					
	Office Action Summary	Examiner	Art Unit					
		Dung (Michael) T. Nguyen	2828					
Period f	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
WHIO - Extending - If No - Fail Any	HORTENED STATUTORY PERIOD FOR REPLICHEVER IS LONGER, FROM THE MAILING Densions of time may be available under the provisions of 37 CFR 1.1 r SIX (6) MONTHS from the mailing date of this communication. O period for reply is specified above, the maximum statutory period vure to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be timwill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	I.  lety filed  the mailing date of this communication.  O (35 U.S.C. § 133).					
Status			·					
· -	,—	s action is non-final. nce except for formal matters, pro						
Disposit	tion of Claims							
5)⊠ 6)⊠ 7)⊠	Claim(s) 1-21 is/are pending in the application 4a) Of the above claim(s) is/are withdray Claim(s) 1-7 and 13-21 is/are allowed. Claim(s) 8-10 is/are rejected. Claim(s) 11 and 12 is/are objected to. Claim(s) are subject to restriction and/or	wn from consideration.						
Applicat	tion Papers							
10)	The specification is objected to by the Examine The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Examine The specification is objected to be specification.	epted or b) objected to by the E drawing(s) be held in abeyance. See tion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).					
Priority	under 35 U.S.C. § 119		•					
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some * c) None of:  1. Certified copies of the priority documents have been received.  2. Certified copies of the priority documents have been received in Application No.  3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.								
Attachmer		_						
2)	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) rmation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:						

Art Unit: 2828

#### **DETAILED ACTION**

## Response to Arguments

Applicant's arguments with respect to claims 8-12 have been considered but are moot in view of the new ground(s) of rejection.

# Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 8 and 10 are rejected under 35 U.S.C. 102(b) as being anticipated by Klem et al. (5679963).

With respect to claim 1, Klem et al. disclose in Fig.1 a tunnel junction (5) having a p-doped GaAs(1-x)Sbx layer (col.3, line 4).

With respect to claim 10, Klem et al. disclose in Fig.1 an n-doped layer of InGaAlAs (same as claimed AlInGaAs).

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person

Application/Control Number: 10/078,473

Art Unit: 2828

having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 9 is rejected under 35 U.S.C. 103(a) as being unpatentable over Klem et al. (5679963) in view of Kopf et al. (5268582).

With respect to claim 9, Klem et al. disclose all limitations of the claim except for the p-dopant of carbon with a concentration greater than 1x19sub19 cm-3.

Kopf et al. teach the p-dopant of carbon with a concentration greater than 1x19sub19 cm-3 (col.1, lines 20-23).

Klem et al. and Kopf et al. are the same analogous art of semiconductor.

It would have been obvious to one having ordinary skill in the art at the time the invention was made to provide Klem et al. what is taught by Kopf et al. in order to have a better formation of compensated materials on the semiconductor devices (col.1, lines 27-28).

#### Allowable Subject Matter

Claims 11-12 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

Klem et al. and Kopf et al. fail to disclose the limitations as claimed in claims 11-12.

Claims 1-7 and 13-21 are allowed.

The following is an examiner's statement of reasons for allowance:

Art Unit: 2828

Claim 1 is allowed over the Klem et al. and Kopf et al. prior art because they fail to teach a method of fabricating a tunnel junction of a VCSEL comprising locating a substrate in an MOCVD chamber and setting a temperature between 500 and 650 degrees C, and growing a tunnel junction GaAs(1-x)Sbx.

Claim 13 is allowed over the Klem et al. and Kopf et al. prior art because they fail to teach a VCSEL comprising an active region having a plurality of quantum wells and a tunnel junction over said active region, wherein said tunnel junction includes GaAs(1-x)Sbx layer. Klem et al. and Kopf et al. only teach said tunnel junction includes GaAs(1-x)Sbx layer using in the semiconductor device not in the laser device.

Claims 2-7 and 14-21 are found allowable due to their dependency of claims 1 and 13.

### Communication Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dung (Michael) T Nguyen whose telephone number is (571) 272-1949. The examiner can normally be reached on 8:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Min Harvey can be reached on (571) 272-1835. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 306-3329.